NSN 5962-01-074-1685

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View Online at https://aerobasegroup.com/nsn/5962-01-074-1685
Body Length:
Between 1.180 inches and 1.220 inches
Body Width:
Between 0.590 inches and 0.610 inches
Body Height:
Between 0.080 inches and 0.120 inches
Maximum Power Dissipation Rating:
1000.0 milliwatts
Operating Tempurature Range:
+0.0/+75.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and monolithic and positive outputs and w/enable and w/decoded output and 3-state output and programmable and
programmed and w/strobe and expandable and bipolar and schottky and medium speed and w/buffered output
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
14 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
5.5 volts power source
Time Rating Per Chacteristic:
60.00 nanoseconds propagation delay time, low to high level output
Memory Device Type:
Rom
Memory Capacity:
Unknown
Test Data Document:
30331-19-186f26 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing
etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
24 printed circuit
Shelf Life:
N/a

Demilitarization: Yes - demil/mli

Unit Of Measure:

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